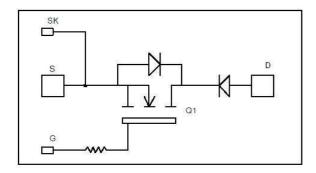


# Single switch with Series diode MOSFET Power Module

$$\begin{split} V_{DSS} &= 1000V \\ R_{DSon} &= 65 m\Omega \text{ typ @ Tj} = 25^{\circ}C \\ I_D &= 145A \text{ @ Tc} = 25^{\circ}C \end{split}$$



#### Application

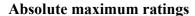
Zero Current Switching resonant mode

#### **Features**

- Power MOS 7<sup>®</sup> MOSFETs
  - Low R<sub>DSon</sub>
  - Low input and Miller capacitance
  - Low gate charge
  - Avalanche energy rated
  - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration
- AlN substrate for improved thermal performance



- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant



Symbol	Parameter		Max ratings	Unit
$V_{ m DSS}$	Drain - Source Breakdown Voltage		1000	V
Ţ	Continuous Drain Current	$T_c = 25$ °C	145	
$I_D$	Continuous Diani Current	$T_c = 80$ °C	110	A
$I_{DM}$	Pulsed Drain current		580	
$V_{GS}$	Gate - Source Voltage	±30	V	
R <sub>DSon</sub>	Drain - Source ON Resistance		78	mΩ
$P_{D}$	Maximum Power Dissipation	$T_c = 25^{\circ}C$	3250	W
$I_{AR}$	Avalanche current (repetitive and non repetitive)		30	A
$E_{AR}$	Repetitive Avalanche Energy		50	ma I
$E_{AS}$	Single Pulse Avalanche Energy	e Energy		mJ

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

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## All ratings @ $T_j = 25$ °C unless otherwise specified

## **Electrical Characteristics**

Symbol	Characteristic	Test Conditions		Min	Тур	Max	Unit
$I_{DSS}$	Zero Gate Voltage Drain Current	$V_{GS} = 0V, V_{DS} = 1000V$	$T_j = 25$ °C			400	μΑ
		$V_{GS} = 0V, V_{DS} = 800V$	$T_j = 125$ °C			2	mA
R <sub>DS(on)</sub>	Drain – Source on Resistance	$V_{GS} = 10V, I_D = 72.5A$			65	78	mΩ
$V_{GS(th)}$	Gate Threshold Voltage	$V_{GS} = V_{DS}$ , $I_D = 20 \text{mA}$		3		5	V
$I_{GSS}$	Gate – Source Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$				±400	nA

## **Dynamic Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$C_{iss}$	Input Capacitance	$V_{GS} = 0V$		28.5		
$C_{oss}$	Output Capacitance	$V_{DS} = 25V$		5.08		nF
$C_{rss}$	Reverse Transfer Capacitance	f = 1MHz		0.9		
$Q_{g}$	Total gate Charge	$V_{GS} = 10V$		1068		
$Q_{gs}$	Gate – Source Charge	$V_{\text{Bus}} = 500 \text{V}$		136		nC
$Q_{gd}$	Gate – Drain Charge	$I_D = 145A$		692		
$T_{d(on)}$	Turn-on Delay Time	$V_{GS} = 15V$		18		
$T_{r}$	Rise Time	$V_{\text{Bus}} = 500 \text{V}$		14		ma
$T_{d(off)}$	Turn-off Delay Time	$I_{D} = 145A$		140		ns
$T_{\mathrm{f}}$	Fall Time	$R_G = 0.75\Omega$		55		
Eon	Turn-on Switching Energy	Inductive switching @ 25°C		4.8		m I
$E_{\text{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 145A, R_G = 0.75\Omega$		2.9		mJ
Eon	Turn-on Switching Energy	Inductive switching @ 125°C		8		m I
$E_{\text{off}}$	Turn-off Switching Energy	$V_{GS} = 15V, V_{Bus} = 670V$ $I_D = 145A, R_G = 0.75\Omega$		3.9		mJ

## Series diode ratings and characteristics

Symbol	Characteristic Test Conditions			Min	Typ	Max	Unit
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			1000			V
T	Maximum Reverse Leakage Current	$V_{\rm p} = 1000V$	$T_j = 25^{\circ}C$			750	Δ
$I_{RM}$			$T_{j} = 125^{\circ}C$			1000	μA
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		240		A
	Diode Forward Voltage	$I_F = 240A$			2	2.5	
$V_{\rm F}$		$I_F = 480A$			2.2		V
		$I_F = 240A$	$T_j = 125$ °C		1.7		
t <sub>rr</sub>	Reverse Recovery Time		$T_j = 25$ °C		280		ns
		$I_F = 240A$ $V_R = 667V$	$T_j = 125$ °C		350		115
Q <sub>rr</sub>	Reverse Recovery Charge	$di/dt = 800A/\mu s$	$T_j = 25$ °C		3.04		μС
		·	$T_{j} = 125^{\circ}C$		14.4		μС

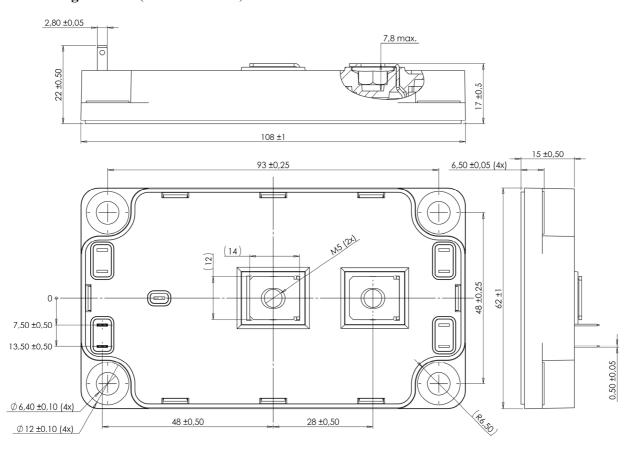
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## Thermal and package characteristics

Symbol	Characteristic			Min	Тур	Max	Unit
$R_{thJC}$	Junction to Case Thermal Resistance		Transistor			0.038	°C/W
KthJC			Series diode			0.23	C/ <b>vv</b>
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000			V
$T_{J}$	Operating junction temperature range			-40		150	
T <sub>STG</sub>	Storage Temperature Range			-40		125	°C
$T_{\rm C}$	Operating Case Temperature			-40		100	
Torque	Mounting torque	To Heatsink	M6	3		5	N.m
		For teminals	M5	2		3.5	IN.III
Wt	Package Weight					300	g

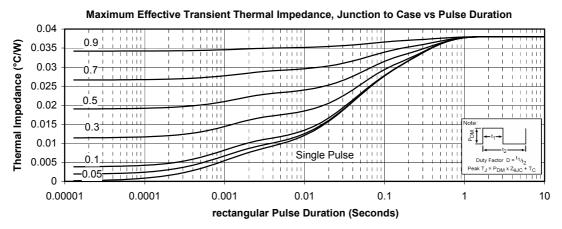
## SP6 Package outline (dimensions in mm)

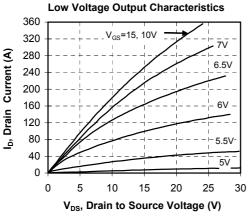


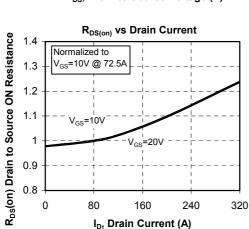
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

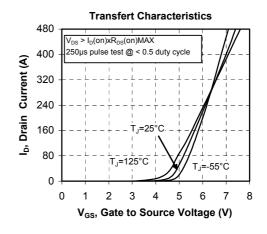


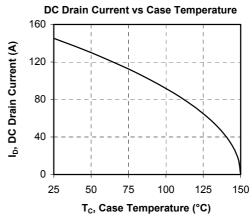
#### **Typical Performance Curve**



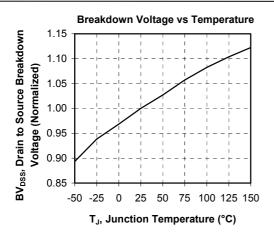


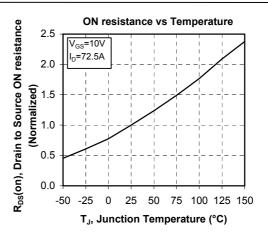


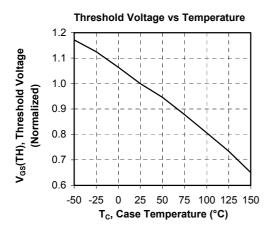


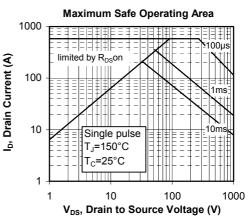


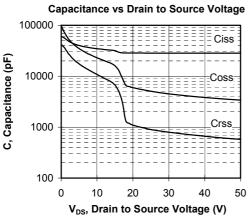


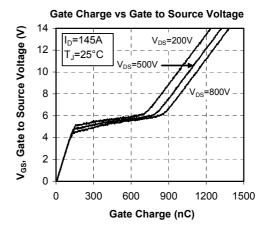




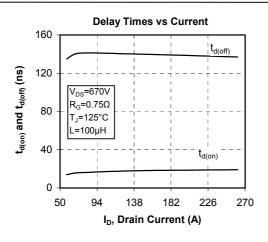


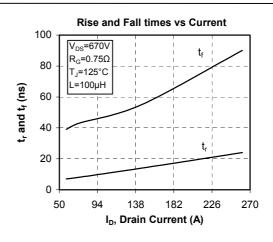


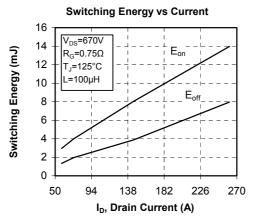


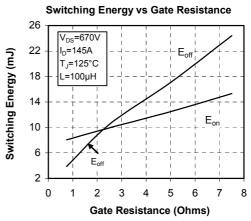


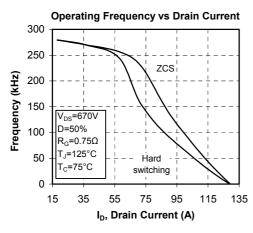


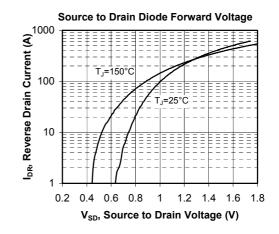














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